

Features

- Unity-gain stable
- Wide bandwidth—60 MHz
- High slew rate—200 V/ μ s
- Wide supply range— ± 5 V to ± 15 V
- Output short circuit protected
- Low supply current—4 mA per amplifier

Applications

- High frequency active filters
- Video amplifiers
- Pulse amplifiers

Ordering Information

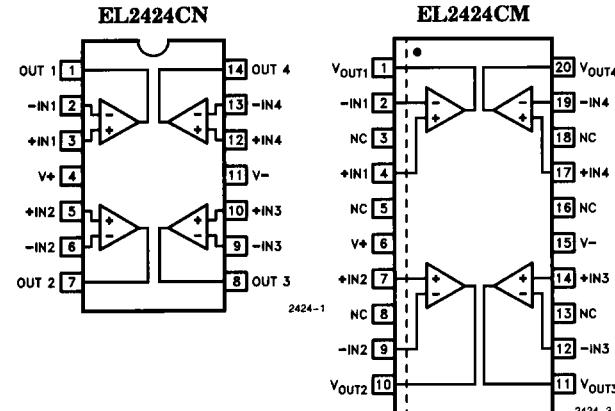
Part No.	Temp. Range	Package	Outline #
EL2424CN	0°C to +75°C	P-DIP	MDP0031
EL2424CM	0°C to +75°C	SOL	MDP0027

General Description

The EL2424 monolithic quad operational amplifier is an example of Elantec's commitment to high speed low power consumption products. This amplifier is unity-gain stable, exhibits Slew Rates of 200V per microsecond, and a Gain Bandwidth of 60 MHz while drawing supply currents of 4 mA per amplifier. The output provides short circuit protection but is capable of delivering currents in excess of 50 mA. The device is manufactured using Elantec's advanced Complementary Bipolar process.

The EL2424 is available in 14-lead Plastic DIP, and 20-pad SOL.

Elantec's products and facilities comply with MIL-I-45082A, and other applicable quality assurance specifications. For information on Elantec's Commercial processing, see QRA-1, "Summary of Elantec's Reliability and Quality Assurance Policy".

Connection Diagrams

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$)

Voltage between V+ and V-	35V	Storage Temperature Range	-65°C to 150°C
Differential Input Voltage	6V	Maximum Junction Temperature	
Peak Output Current	Short Circuit Protected	Plastic DIP, SOL	150°C
Output Short Circuit Duration (Note 1)	Continuous	Lead Temperature	
Internal Power Dissipation	See Curves	DIP Package	300°C
Operating Temperature Range	0°C to +75°C	SOL Package	
		Vapor Phase (60 seconds)	215°C
		Infrared (15 seconds)	220°C

Important Note:

All parameters having Min/Max specifications are guaranteed. The Test Level column indicates the specific device testing actually performed during production and Quality Inspection. Electro performance must electrical tests using modern high-speed automatic test equipment, specifically the LTX77 Series system. Unless otherwise noted, all tests are pulsed tests, therefore $T_J = T_C = T_A$.

Test Level	Test Procedure
I	100% production tested and OA sample tested per OA test plan QCX0002.
II	100% production tested at $T_A = 25^\circ\text{C}$ and OA sample tested at $T_A = 25^\circ\text{C}$, T_{MAX} and T_{MIN} per OA test plan QCX0002.
III	QA sample tested per OA test plan QCX0002.
IV	Parameter is guaranteed (but not tested) by Design and Characterization Data.
V	Parameter is typical value at $T_A = 25^\circ\text{C}$ for information purposes only.

1

DC Electrical Characteristics $V_S = \pm 15\text{V}$; $R_L = 2\text{k}\Omega$, unless otherwise specified

Parameter	Description	Temp	EL2424C			Units
			Min	Typ	Max	
V_{OS}	Offset Voltage	25°C		6	15	I
		Full			20	III
TCV_{OS}	Average Offset Voltage Drift	Full		50		V
I_B	Bias Current	25°C		1.0	4	I
		Full			6	III
I_{OS}	Offset Current	25°C		0.5	2	I
		Full			3	III
R_{IN}	Input Resistance	25°C		20		V
C_{IN}	Input Capacitance	25°C		1		pF
V_{CM}	Common Mode Input Range	Full	± 10	± 11		V
e_{IN}	Input Noise Voltage ($f = 1\text{ kHz}$, $R_G = 0\Omega$)	25°C		7		nV/ $\sqrt{\text{Hz}}$
AVOL	Large Signal Voltage Gain (Notes 2, 3)	25°C	5k	13k		I
		Full	4k			III
CMRR	Common-Mode Rejection Ratio (Note 4)	Full	70	87		dB

EL2424C

Quad 60 MHz High Speed Operational Amplifier

DC Electrical Characteristics $V_S = \pm 15V$; $R_L = 2 k\Omega$, unless otherwise specified — Contd.

Parameter	Description	Temp	EL2424C				Units
			Min	Typ	Max	Test Level	
V_O	Output Voltage Swing	Full	± 11	± 13		II	V
I_{SC}	Short Circuit Current	$25^\circ C$	± 10	± 50	± 85	I	mA
R_O	Output Resistance	$25^\circ C$		40		V	Ω
I_S	Supply Current	Full		14	18	II	mA
PSRR	Power Supply Rejection Ratio (Note 5)	Full	60	80		II	dB

AC Electrical Characteristics $V_S = \pm 15V$; $R_L = 2 k\Omega$, unless otherwise specified

Parameter	Description	Temp	EL2424C				Units
			Min	Typ	Max	Test Level	
f_u	Open Loop Unity Bandwidth (Note 6)	$25^\circ C$		60		V	MHz
FPBW	Full Power Bandwidth (Note 7)	$25^\circ C$	2.4	3.2		I	MHz
t_r	Rise Time (Note 6)	$25^\circ C$		7		V	ns
OS	Overshoot (Note 6)	$25^\circ C$		20		V	%
SR	Slew Rate (Note 10)	$25^\circ C$	150	200		I	V/ μ s
t_s	Settling Time (Note 9) 10V Step to 0.05%	$25^\circ C$		330		V	ns
CHSp	Channel Separation $f = 1$ MHz	$25^\circ C$		65		V	dB

Note 1: A heat sink is required to keep the junction temperature below absolute maximum when the output is shorted.

Note 2: $V_O = \pm 10V$.

Note 3: $R_L = 2k\Omega$.

Note 4: Two tests are performed. $V_{CM} = 0V$ to $+10V$ and $V_{CM} = 0V$ to $-10V$.

Note 5: Two tests are performed. $V+ = 15V$, and $V-$ is changed from $-5V$ to $-15V$. $V- = -15V$, and $V+$ is changed from $+5V$ to $+15V$.

Note 6: $V_O = 100$ mV.

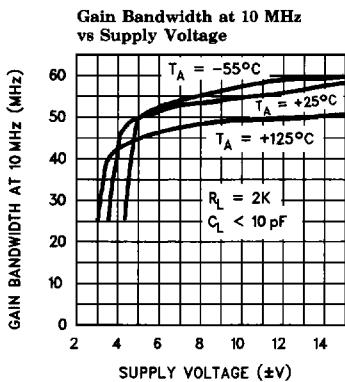
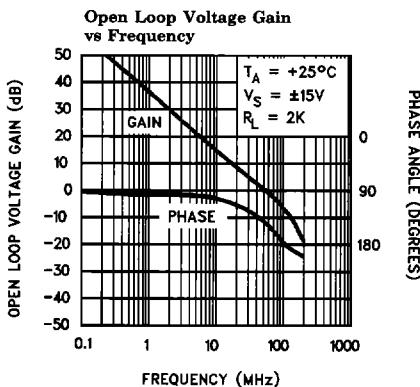
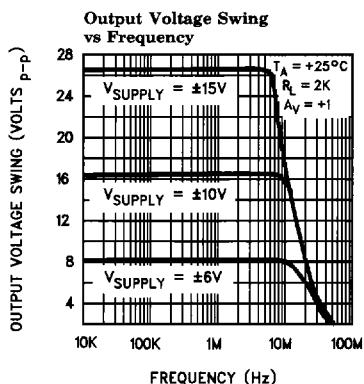
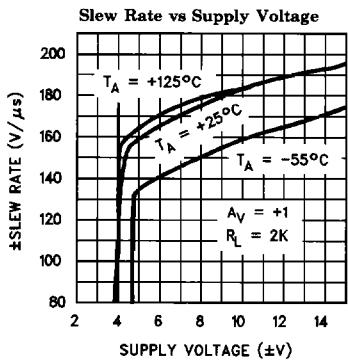
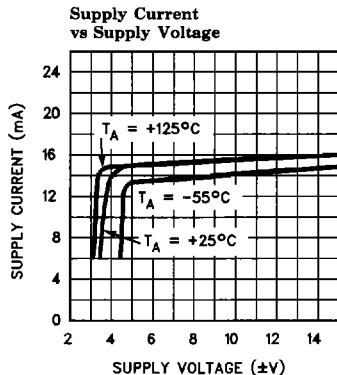
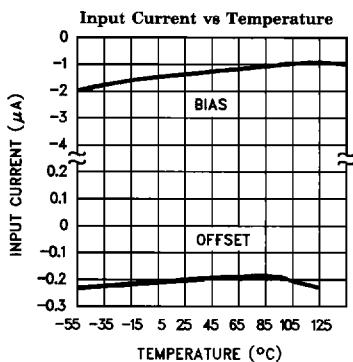
Note 7: Full Power Bandwidth guaranteed based on slew rate measurement using: $FPBW = \text{Slew Rate}/2\pi V_{peak}$.

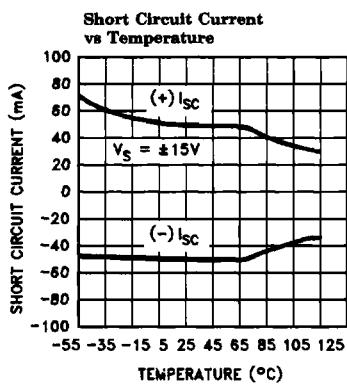
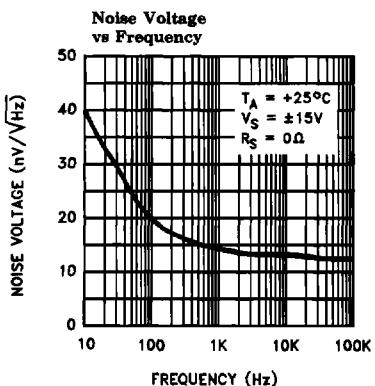
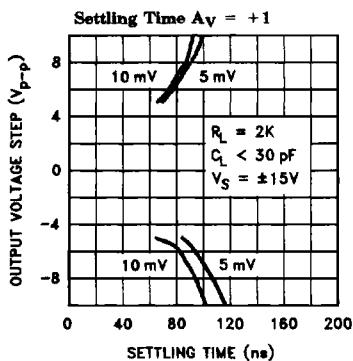
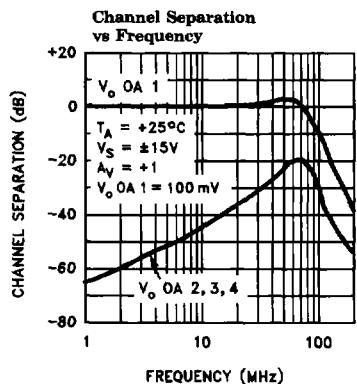
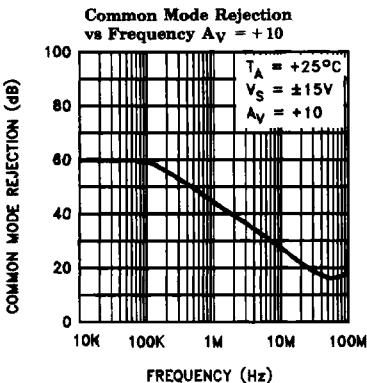
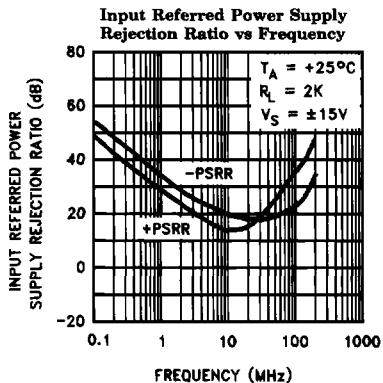
Note 8: Refer to Test Circuit section of data sheet.

Note 9: Settling time measurements are made with techniques in the following reference: "Take The Guesswork Out of Settling-Time Measurements," EDN September 19, 1985.

Note 10: $V_O = \pm 10V$.

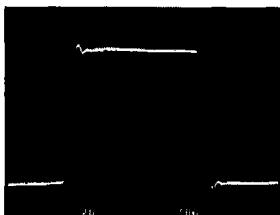
Typical Performance Curves



EL2424C**Quad 60 MHz High Speed Operational Amplifier****Typical Performance Curves — Contd.**

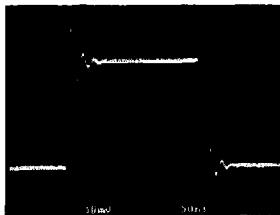
Typical Performance Curves — Contd.

Large Signal Response

 $A_V = +1$ $V_{IN} = \pm 5V$ $V_O = \pm 5V$ $R_L = 2k$

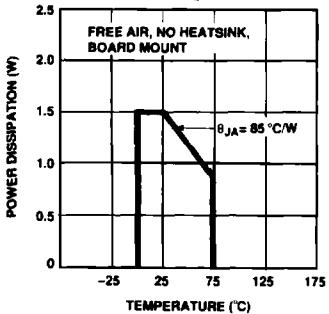
2424-6

Small Signal Response

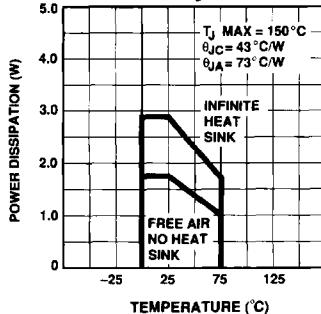
 $A_V = +1$ $V_{IN} = \pm 100 mV$ $V_O = \pm 100 mV$ $R_L = 2k$

2424-7

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20-Lead SOL
Maximum Power Dissipation
vs Ambient Temperature

2424-8

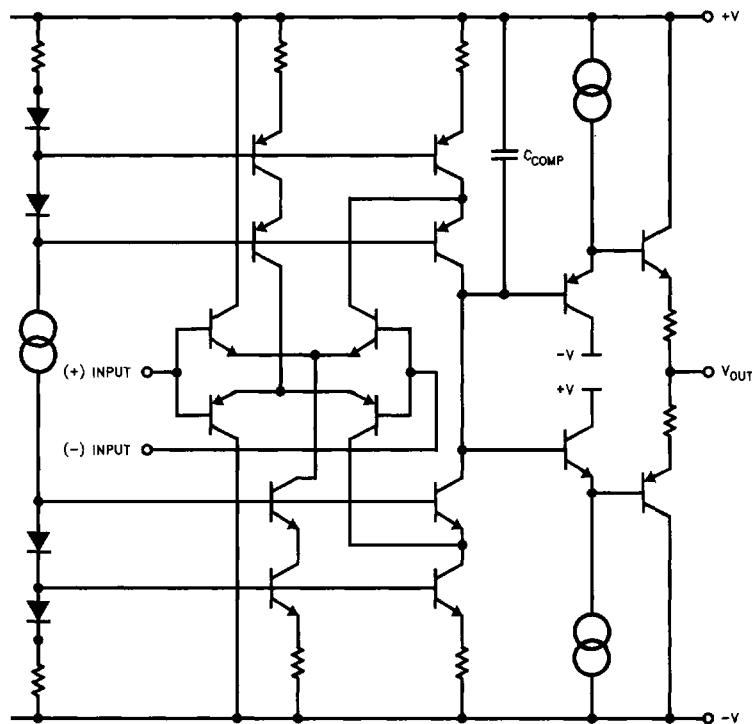
14-Lead Plastic DIP
Maximum Power Dissipation
vs Ambient Temperature

2424-9

EL2424C

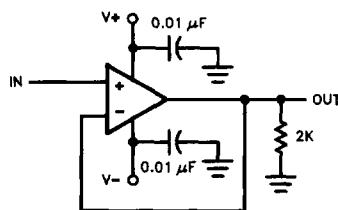
Quad 60 MHz High Speed Operational Amplifier

Simplified Schematic (One Amplifier)



2424-11

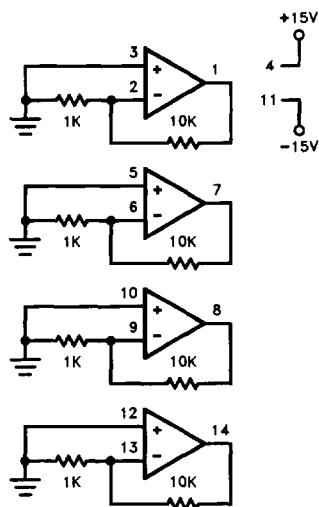
Test Circuit



2424-12

Pin numbers indicated are for the 14-lead DIP. Circuit is identical for all package types.

Burn In Circuit

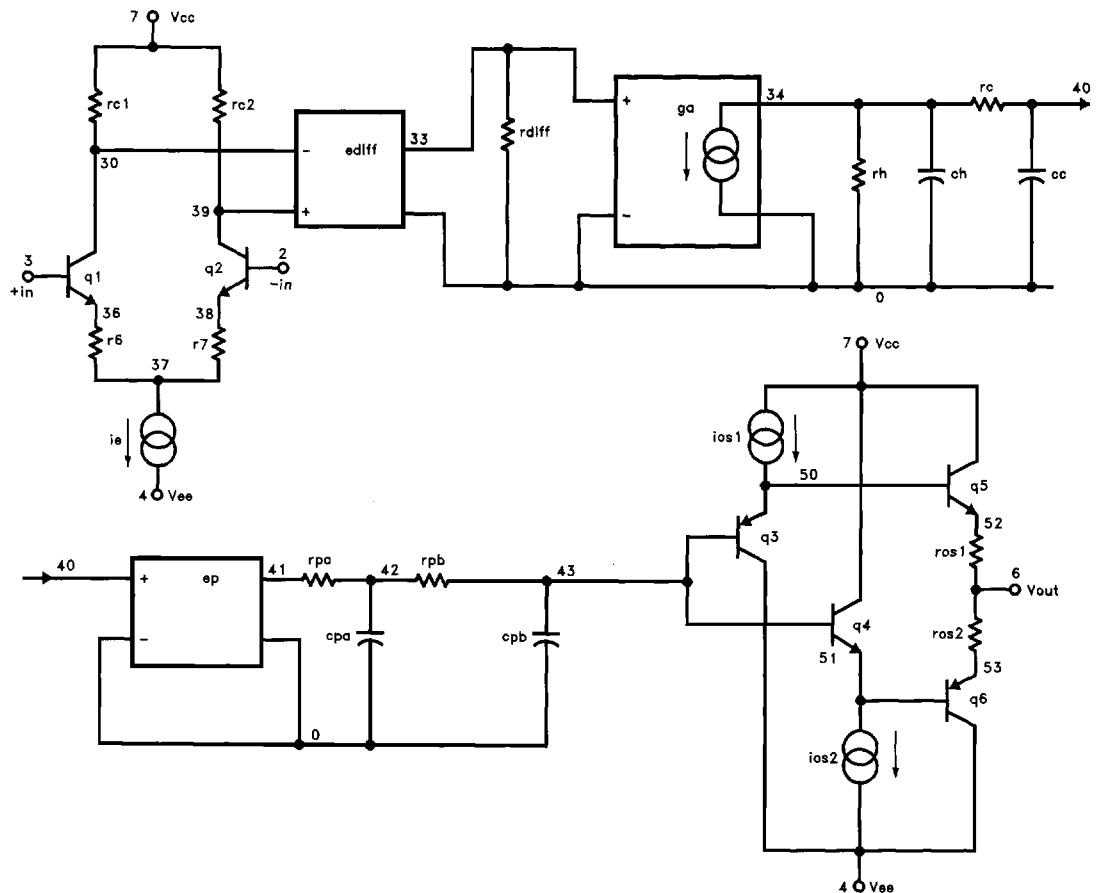


2424-13

EL2424C Macromodel

* Connections: + input
 * | - input
 * | | + Vsupply
 * | | - Vsupply
 * | | | output
 * | | |
 .subckt M2424 3 2 7 4 6

* Input stage
 ie 37 4 4.5mA
 r6 36 37 75
 r7 38 37 75
 rcl 7 30 75
 rc2 7 39 75
 q1 30 3 36 qn
 q2 39 2 38 qna
 ediff 33 0 39 30 2.6
 rdifff 33 0 1Meg
 * Compensation Section
 ga 0 34 33 0 3m
 rh 34 0 1Meg
 ch 34 0 15pF
 rc 34 40 300
 cc 40 0 1pF
 * Poles
 ep 41 0 40 0 1
 rpa 41 42 75
 cpa 42 0 3pF
 rpb 42 43 50
 cpb 43 0 3pF
 * Output Stage
 ios1 7 50 0.5mA
 ios2 51 4 0.5mA
 q3 4 43 50 qp
 q4 7 43 51 qn
 q5 7 50 52 qn
 q6 4 51 53 qp
 ros1 52 6 25
 ros2 6 53 25
 * models
 .model qn npn(is = 800.0E - 18 bf = 350 tf = 0.2nS)
 .model qna npn(is = 864E - 18 bf = 400 tf = 0.2nS)
 .model qp pnp(is = 800E - 18 bf = 60 tf = 0.2nS)
 .ends

EL2424C Macromodel — Contd.

2424-14